2SAR533P / 2SAR533D

PNP -3.0A -50V Middle Power Transistor

Datasheet

Collector

Emitter

2SAR533D

(SC-63)

<SOT-428>

CPT3

Base

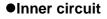
Parameter	Value
V _{CEO}	-50V
Ι _C	-3.0A

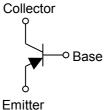
Features

- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types: 2SCR533P / 2SCR533D
- 3) Low V_{CE(sat)}

 $V_{CE(sat)} = -0.4V$ Max. $(I_C/I_B = -1A/-50mA)$

4) Lead Free/RoHS Compliant.





Applications

Outline

Base

Collector

Emitter

2SAR533P

(SC-62)

<SOT-89>

MPT3

Motor driver , LED driver Power supply

Packaging specif	ications						
Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SAR533P	MPT3	4540	T100	180	12	1,000	MM
2SAR533D	CPT3	6595	TL	330	16	2,500	AR533

●Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V _{CBO}	-50	V
Collector-emitter voltage		V _{CEO}	-50	V
Emitter-base voltage		V _{EBO}	6	V
Collector current	DC	Ι _C	-3.0	Α
	Pulsed	I _{CP} ^{*1}	-6.0	Α
	2SAR533P		0.5 ^{*2}	W
Power dissipation	23AR333F		2.0 ^{*3}	W
rower dissipation	2SAR533D	'D	1.0 ^{*4}	W
	23AR333D		10 ^{*5}	W
Junction temperature		Tj	150	°C
Range of storage temperature		T _{stg}	−55 to +150	°C

*1 Pw=10ms, single pulse *2 Each terminal mounted on a reference land

*3 Mounted on a ceramic board (40×40×0.7mm) *4 Mounted on a substrate *5 T_C=25°C

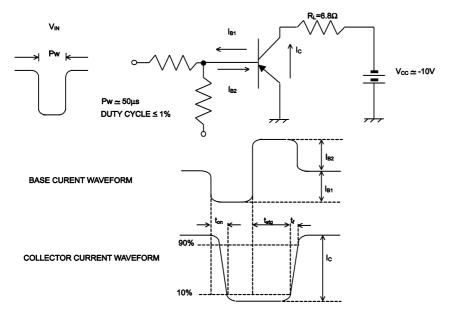
•Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	I _C = -1mA	-50	-	-	V
Collector-base breakdown voltage	BV _{CBO}	I _C = -100μA	-50	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	I _E = -100μA	-6	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} = -50V	-	-	-1	μA
Emitter cut-off current	I _{EBO}	V _{EB} = -4V	-	-	-1	μA
Collector-emitter saturation voltage	V _{CE(sat)} ^{*1}	$I_{\rm C} = -1$ A, $I_{\rm B} = -50$ mA	-	-0.20	-0.40	V
DC current gain	h _{FE}	$V_{CE} = -3V, I_{C} = -50mA$	180	-	450	-
Transition frequency	f_{T}	V _{CE} = -10V, I _E = -500mA f=100MH _Z	-	300	-	MHz
Output capacitance	C _{ob}	V _{CB} = -10V, I _E = 0A f = 1MHz	-	24	-	pF
Turn-on time	t _{on} *2	I _C = –1.5A	-	45	-	ns
Storage time	t _{stg} *2	I _{B1} = –150mA I _{B2} =150mA	-	250	-	ns
Fall time	t _f *2	V _{CC} ≃ −10V	-	35	-	ns

*1 Pulsed

*2 See switching time test circuit

•Switching time test circuit



-2

•Electrical characteristic curves(Ta = 25°C)

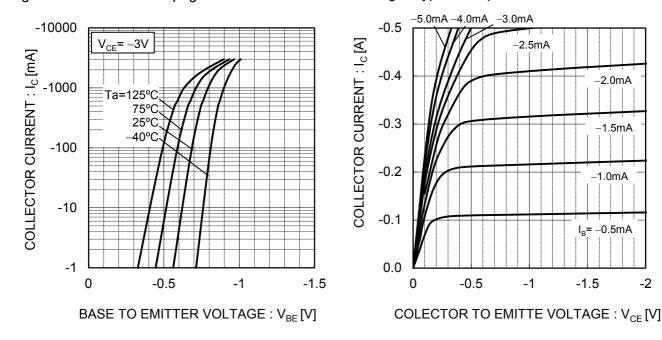
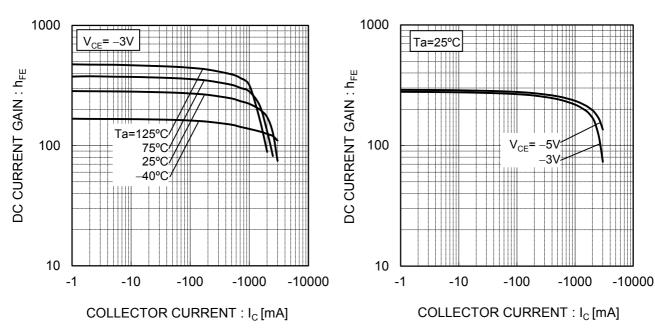


Fig.1 Ground Emitter Propagation Characteristics

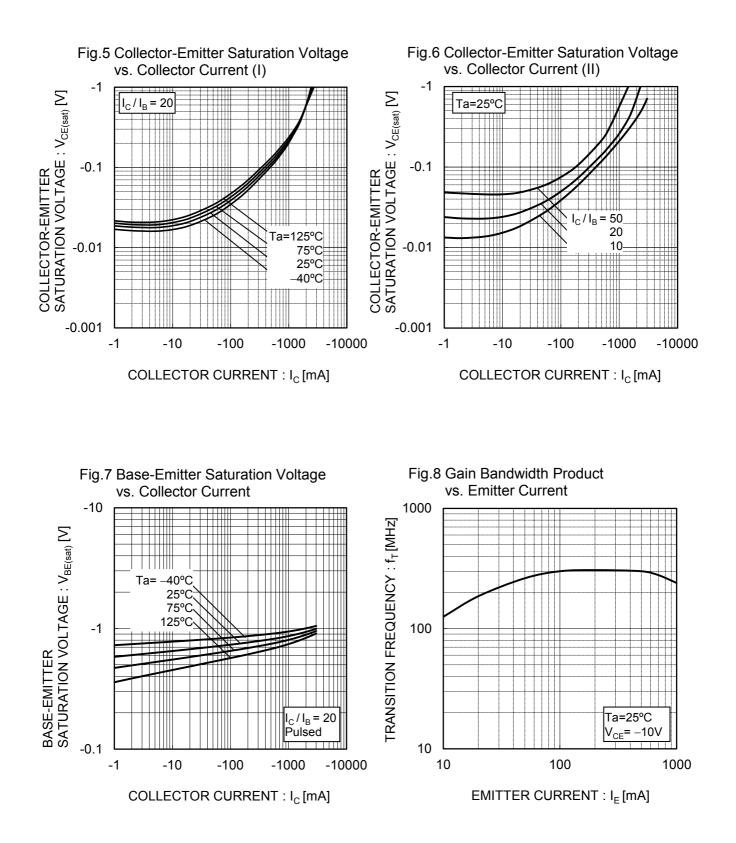
Fig.3 DC Current Gain vs. Collector Current(I)

Fig.4 DC current gain vs. output current (II)

Fig.2 Typical Output Characteristics



•Electrical characteristic curves(Ta = 25°C)



•Electrical characteristic curves(Ta = 25°C)

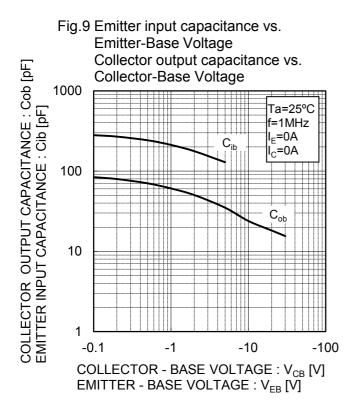


Fig.10 Safe Operating Area

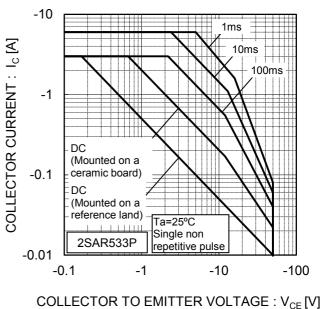
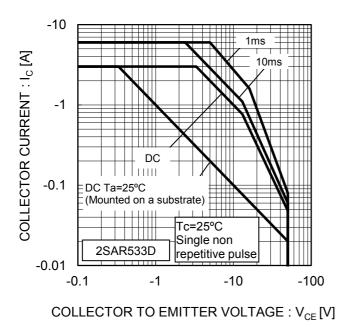
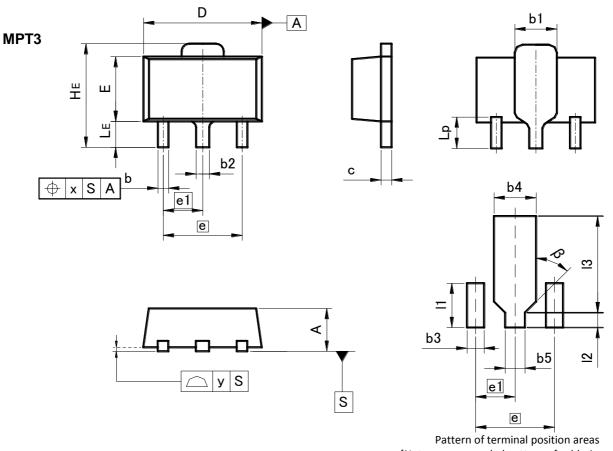


Fig.11 Safe Operating Area



•Dimensions (Unit : mm)

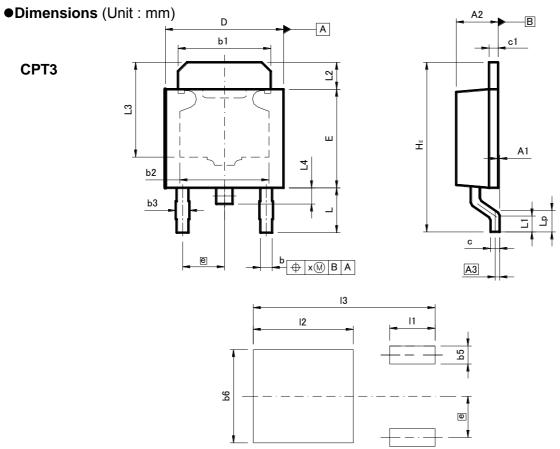


[Not a recommended pattern of soldering pads]

		ETERS	INC	HES	
DIN	MIN	MAX	MIN	MAX	
A	1.40	1.50	0.055	0.059	
b	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
С	0.35	0.50	0.014	0.020	
D	4.40	4.70	0.173	0.185	
E	2.40	2.70	0.094	0.106	
е	3.0	00	0.118		
e1	1.	50	0.059		
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
х	_	0.15	-	0.006	
У	_	0.10	_	0.004	

DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
b3	-	0.65	-	0.026
b4	-	1.70	-	0.067
b5	-	0.75	-	0.030
1		1.71	-	0.067
12		0.58	-	0.023
13	_	3.72	_	0.146
β	45	0	45	0

Dimension in mm / inches



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
A1	0.00	0.15	0.000	0.006
A2	2.20	2.50	0.087	0.098
A3	0.	25	0.0	10
b	0.55	0.75	0.022	0.030
b1	5.00	5.30	0.197	0.209
b2	5.	00	0.1	97
b3	0.	75	0.0	30
С	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.30	6.70	0.248	0.264
E	5.40	5.80	0.213	0.228
е	2.	30	0.0	91
HE	9.00	10.00	0.354	0.394
L	2.20	2.80	0.087	0.110
L1	0.80	1.40	0.031	0.055
L2	1.20	1.80	0.047	0.071
L3	5.30		0.209	
L4	0.90		0.0	35
Lp	1.00	1.60	0.039	0.063
х	_	0.25	_	0.010

DIM	MILIM	ETERS	INCHES	
DIM	MIN	MAX	MIN	MAX
b5	-	1.00	-	0.04
b6	-	5.20	-	0.205
11	-	2.50	-	0.098
12	-	5.50	-	0.217
13	-	10.00	-	0.394

Dimension in mm / inches

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